

# PUMD14

# 50 V, 100 mA NPN/PNP resistor-equipped transistor; R1 = 47 k $\Omega$ , R2 = open

27 April 2023

Product data sheet

### 1. General description

NPN/PNP Resistor-Equipped Transistor (RET) in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

PNP/PNP complement: PUMB14 NPN/NPN complement: PUMH14

#### 2. Features and benefits

- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- · Reduces pick and place cost
- AEC-Q101 qualified

# 3. Applications

- Low current peripheral driver
- · Control of IC inputs
- · Replacement of general-purpose transistors in digital applications

#### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor	Per transistor						
V <sub>CEO</sub>	collector-emitter voltage	open base	[1]	-	-	50	V
Io	output current		[1]	-	-	100	mA
R1	bias resistor 1 (input)		[2]	33	47	61	kΩ

- [1] For the PNP transistor with negative polarity.
- [2] See section "Test information" for resistor calculation and test conditions.



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# 5. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		O1 I2 GND2
2	I1	input (base) TR1	□6 □5 □4	
3	O2	output (collector) TR2		
4	GND2	GND (emitter) TR2		TR1
5	12	input (base) TR2	H <sub>1</sub> H <sub>2</sub> H <sub>3</sub>	R1
6	O1	output (collector) TR1	TSSOP6 (SOT363)	GND1 I1 O2 006aaa269

# 6. Ordering information

**Table 3. Ordering information** 

Type number	Package				
	Name	Description	Version		
PUMD14		plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	<u>SOT363</u>		

# 7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PUMD14	T2%

[1] % = placeholder for manufacturing site code

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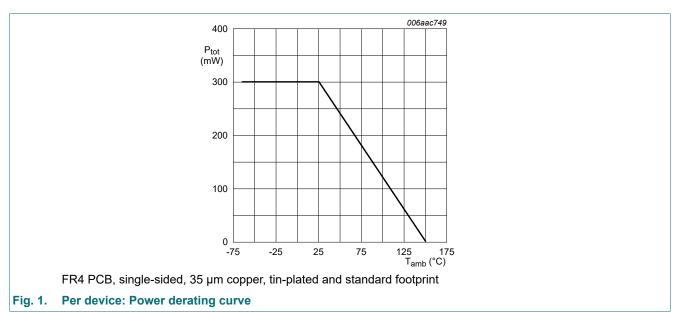
# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or		'			
V <sub>CBO</sub>	collector-base voltage	open emitter	[1]	-	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	[1]	-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	[1]	-	5	V
VI	input voltage	TR1 (NPN)		-5	40	V
		TR2 (PNP)		-40	5	V
Io	output current		[1]	-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[2]	-	200	mW
Per device			'	·		
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[2]	-	300	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

- [1] For the PNP transistor with negative polarity.
- [2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



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### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor	Per transistor						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W
Per device	Per device						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	416	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

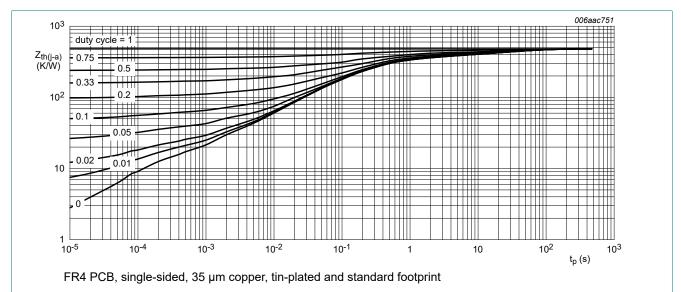


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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# 10. Characteristics

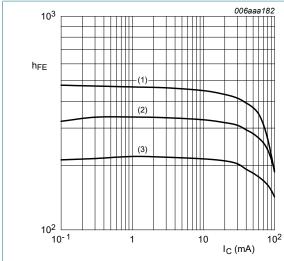
**Table 7. Characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or						<b>-</b>
V <sub>(BR)CBO</sub>	collector-base breakdown voltage	$I_C = 100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$	[1]	50	-	-	V
V <sub>(BR)CEO</sub>	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	[1]	50	-	-	V
I <sub>CBO</sub>	collector-base cut-off current	V <sub>CB</sub> = 50 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	[1]	-	-	100	nA
I <sub>CEO</sub>	collector-emitter cut-off	V <sub>CE</sub> = 30 V; I <sub>B</sub> = 0 A; T <sub>amb</sub> = 25 °C	[1]	-	-	1	μA
	current	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}; T_{j} = 150 ^{\circ}\text{C}$	[1]	-	-	50	μA
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C	[1]	-	-	100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 1 mA; T <sub>amb</sub> = 25 °C	[1]	100	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}; T_{amb} = 25 \text{ °C}$	[1]	-	-	150	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5 \text{ V}; I_{C} = 0.1 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$	[1]	-	0.6	0.5	V
$V_{I(on)}$	on-state input voltage	$V_{CE} = 0.3 \text{ V}; I_{C} = 10 \text{ mA}$	[1]	4	2.5	-	V
R1	bias resistor 1 (input)		[2]	33	47	61	kΩ
Transistor T	R1 (NPN)			·		·	
C <sub>c</sub>	collector capacitance	$V_{CB}$ = 10 V; $I_{E}$ = 0 A; $i_{e}$ = 0 A; f = 1 MHz; $T_{amb}$ = 25 °C		-	-	2.5	pF
f <sub>T</sub>	transition frequency	$V_{CE}$ = 5 V; $I_{C}$ = 10 mA; f = 100 MHz; $T_{amb}$ = 25 °C	[3]	-	230	-	MHz
Transistor T	R2 (PNP)			'			
C <sub>c</sub>	collector capacitance	$V_{CB}$ = -10 V; $I_{E}$ = 0 A; $i_{e}$ = 0 A; $f$ = 1 MHz; $T_{amb}$ = 25 °C		-	-	3	pF
f <sub>T</sub>	transition frequency	$V_{CE}$ = -5 V; $I_{C}$ = -10 mA; f = 100 MHz; $T_{amb}$ = 25 °C	[3]	-	180	-	MHz
	-						

For the PNP transistor with negative polarity.
See section "Test information" for resistor calculation and test conditions.

<sup>[2]</sup> [3] Characteristics of built-in transistor

#### 50 V, 100 mA NPN/PNP resistor-equipped transistor; R1 = 47 k $\Omega$ , R2 = open



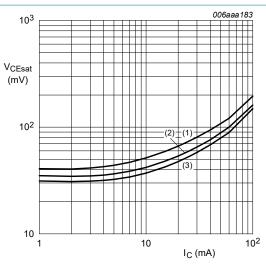
$$V_{CE} = 5 V$$

$$(1) T_{amb} = 100 ° ($$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(1) T<sub>amb</sub> = 100 °C (2) T<sub>amb</sub> = 25 °C (3) T<sub>amb</sub> = -40 °C

TR1 (NPN): DC current gain as a function of Fig. 3. collector current; typical values

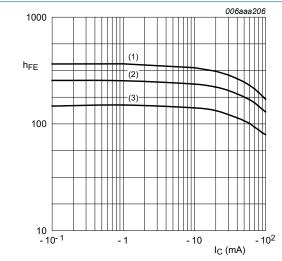


$$I_{\rm C}/I_{\rm B} = 20$$

$$I_{C}/I_{B} = 20$$
(1)  $T_{amb} = 100 \, ^{\circ}C$ 
(2)  $T_{amb} = 25 \, ^{\circ}C$ 
(3)  $T_{amb} = -40 \, ^{\circ}C$ 

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

Fig. 4. TR1 (NPN): Collector-emitter saturation voltage as a function of collector current; typical values



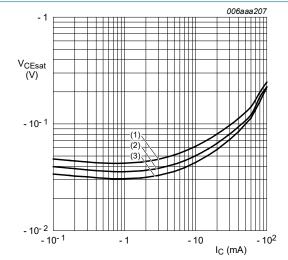
$$V_{CE}$$
 = -5  $V$ 

$$(1) T_{amb} = 100 °C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) T<sub>amb</sub> = -40 °C

TR2 (PNP): DC current gain as a function of Fig. 5. collector current; typical values



$$I_{\rm C}/I_{\rm B} = 20$$

$$(1) T_{amb} = 100 °C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3)  $T_{amb} = -40 \, ^{\circ}C$ 

Fig. 6. TR2 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values

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## 11. Test information

#### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

#### **Resistor calculation**

Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{I})}{I_{2} - I_{I}}$$

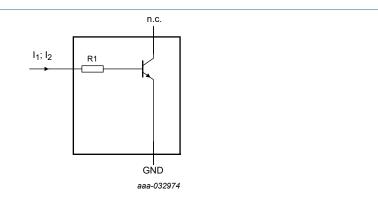


Fig. 7. TR1 (NPN): Resistor test circuit

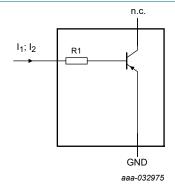


Fig. 8. TR2 (PNP): Resistor test circuit

#### **Resistor test conditions**

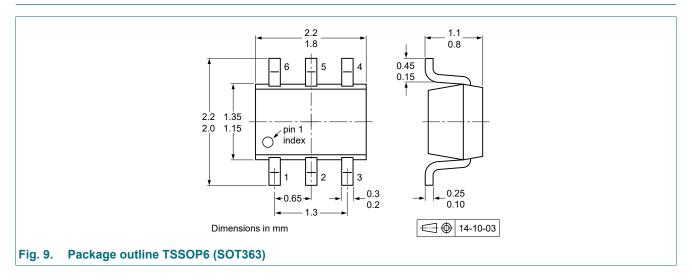
**Table 8. Resistor test conditions** 

PUMD4	R1 (kΩ)	R2 (open)	Test conditions	
			I <sub>1</sub>	l <sub>2</sub>
TR1 (NPN)	47	-	55 μA	105 μΑ
TR2 (PNP)	47	-	-55 μA	-105 μA

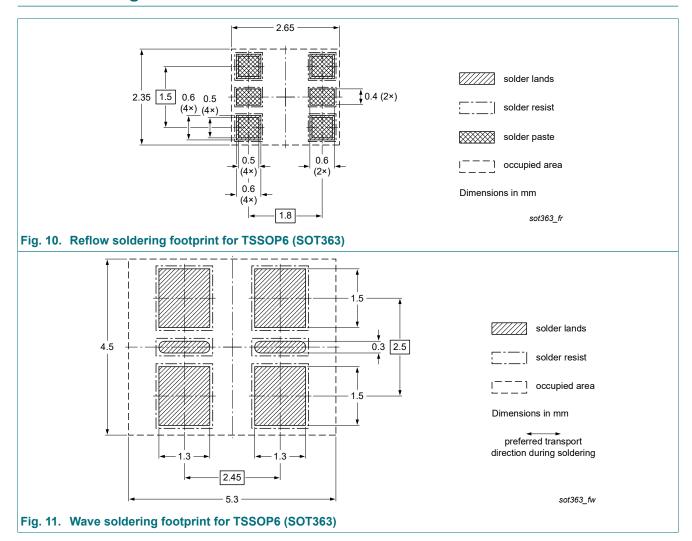
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# 12. Package outline



## 13. Soldering



50 V, 100 mA NPN/PNP resistor-equipped transistor; R1 = 47 k $\Omega$ , R2 = open

# 14. Revision history

#### Table 9. Revision history

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Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PUMD14 v.3	20230427	Product data sheet	-	PEMD14_PUMD14_2		
Modifications:	Nexperia.  Legal texts have bee Family data sheet re	ormat of this data sheet has been redesigned to comply with the identity guidelines				
PEMD14_PUMD14_2	20090902	Product data sheet	-	PEMD14_PUMD14_1		
PEMD14_PUMD14_1	20050114	Product data sheet	-	-		

#### 50 V, 100 mA NPN/PNP resistor-equipped transistor; R1 = 47 k $\Omega$ , R2 = open

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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